

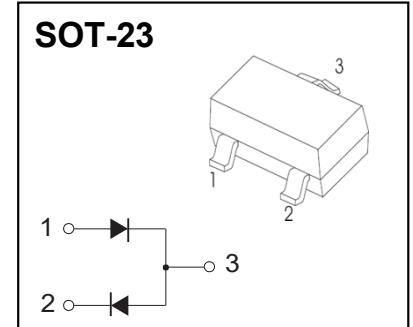
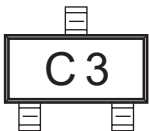
SOT-23 Plastic-Encapsulate Diodes

1SS226 SWITCHING DIODE

FEATURES

- Low forward voltage
- Fast reverse recovery time
- Small total capacitance

Marking: C3



Maximum Ratings @Ta=25°C

Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	85	V
DC Blocking Voltage	V_R	80	V
Forward Continuous Current	I_{FM}	300	mA
Average Rectified Output Current	I_O	100	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I_{FSM}	2.0	A
Power Dissipation	P_D	150	mW
Operation Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	$I_R = 100\mu A$	80		V
Reverse voltage leakage current	I_R	$V_R = 80V$		0.5	μA
Forward voltage	V_F	$I_F = 100mA$		1.2	V
Diode capacitance	C_D	$V_R = 0, f = 1MHz$		3	pF
Reverse recovery time	t_{rr}	$I_F = I_R = 10mA$		4	ns

Typical Characteristics

